

Scientific writing

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Lecture aim



- I want to give you a brief tour of how to write scientific* text and how scientific* publishing works.
- Think of this as a crash course in scientific writing.
- This is derived from my own experiences, so it's useful advice and tips not just some theory.

*For scientific read Engineering, Biological, Medical etc..





• By the end of the lecture I want you to understand that:

Scientific writing/publishing is very different to other forms of writing/publishing.



Lecture outline



- The process of knowledge dissemination
- What's the point of references
- Clarity of writing
- Figures and graphs
- How to write a scientific paper
- How to write a scientific report
- How to write a thesis
- How do do a literature review

Lecture outline



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How do you get your good idea out to the world?



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Idea/New exciting data

• This is the problem we need to solve.

How do you get your good idea out to the world?



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- Facebook
- Whasapp
- E-mail
- Youtube
- Periscope
- A random blog

How do you get your good idea out to the world?

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- These are pretty good ways to decimate inform about dancing kittens and south Korean pop music.





- However, the problem with them is that nobody checks if what you are saying is correct.
- It is therefore not taken seriously.

So how do Scientists and Engineers decimate information?



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Step 1: Performing the experiment



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• The first step is to gather data and understand the results:







Step 2: Generating a paper...



• Once you have your data or new theory you write it up in draft paper (which we will talk about later).

Combining Plasmonic Trap Filling and Optical Backscattering for Highly

Efficiency Third Generation Solar Cells.

Chen Mang^a, Yajun Gag^a, Shanpeng Mén^a,* Pengfei Ma^a, Roderick C. I. <u>MacKenzie</u>,*

Shengping Ruan²

a) Gollage of Electronic Schero and Bigheering, Jillin University Changchan 130012, P.R. China b) <u>Sprenging at Johns II. Proposition by Security 2015 (2015)</u>, 2017, 2018 <u>2018</u>, Gennary c) Braulty of Bigheering, The University of Natingham, University Posk, Natingham, NK772RD, UK <u>any</u> contributions: <u>Polyteck Web wire drawning drawn as di</u>.

Abs tract

Metal oxide contact layers such as 200 and TiQx are commonly used in third generation solar cells as they can be solution processed and have a relatively high conductivity. It is well known, that by light soaking such devices overall device efficiency can be boosted. This improvement in efficiency is due to high energy UV light exciting hot carriers which then fill trap states in the metal oxide film. Unfortunately, UV causes degradation of the active layer and thus must be filter out if long lifetimes are to be achieved. In this work, we use <u>nano-structures</u> embedded in the 200 metal oxide layer to generate hot charge carriers from visible light alone, thus removing the heed for UV light soaking. Using this approach, we demonstrate that the power conversion efficiency of a <u>low-</u> <u>bands up thieno[3,4-b]thiophene@enrodithiophene</u> (PTB7) based solar cell can be increased from 7.91% to 9.36%.

Introduction

Plasmonic panostructures such as metallic panoparticles (MMPs) have recently attracted considerable interest for their ability to support localized surface plasmon resonances (LSPR).¹⁻³ By exploiting size-function relationships the optical properties of the panoparticles can be easily tuned¹⁺⁶, making them suitable for <u>optoelectronic</u> applications such as photo-detectors² and solar cells¹⁰. In particular, the highly confined LSPR modes provide a feasible strategy for bulk <u>heterojunction</u> (BHJ) organic solar cells (OSCs) to achieve better optical absorption without increasing the thickness of organic layer.¹⁰ It is well known that when integrated into <u>OSCs</u>, these metal <u>pano-particles</u> can act Generally speaking this is a normal MS Word (Libre office) document, which is double spaced so people can write on it.



Chen Wang^a, Yajun Gao^b, Shanpeng Wen^a,* Pengfei Ma^a, Roderick C. I. MacKenzie^c,* Shengping Ruan^a

- 1st: The person who did the work*
- 2nd: The person who helped in the lab.
- Other people who helped a bit
- Second last: Co supervisor or someone fairly important but did not get the money for the experiment.
- Last: The person who funded the work*

 *These are the most important places to have your name, and you can upset people a lot by insisting you name has to be in a set position!

Author order and what it means..



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JORGE





WWW. PHDCOMICS. COM

Corresponding author



• If you look at this list, you can see a star above some names.

Yajun Gao, Roderick C. I. MacKenzie,* Yang Liu, Bin Xu, Paul H. M. van Loosdrecht,* and Wenjing Tian*

- These are the **corresponding authors**
- These are the people **you can e-mail** if you have questions about the paper they may even respond to e-mails about their work (if the questions are intelligent/polite).
- In UK academic culture people generally, **don't care who is corresponding author**. And it's often the person who just has the job of writing letters to the editor.
- In other academic cultures, corresponding author matters and even the order of the corresponding authors matters (China).

Now send your paper to the co-authors for comment.



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- Be patient with them but firm.
- They are very busy people.

Combining Plasmonic Trap Filling and Optical Backscattering for Highly

Efficiency Third Generation Solar Cells

Chen Yeng", Yajun Gao", Shanpeng Yen", * Pengfei Ma", Raderick C. I. MacKenzie', Shenaping Rusn²

a) Galligo of Electronic Sómor and Baglaweing, Jilin University Changchus 13002, F.R. China b) <u>Lightegolig</u> at <u>Jölja</u>, <u>B. Zythejdegh Jaglav, Zijhlegh Jaj</u>, *T. SmBT Jolg, Camary* c) Brahly of Baglaweing, *Buc University of Natinghum*, University Park, Natingham, MG7 2RD, UK * <u>A spectrational in Electric Solution Control Annual An</u>

Abs tract

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Introduction

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co- authors

Contradictory suggestions/ do more measurements



- They will then send you back changes and suggestions to the paper using track changes.
- Your paper can go back and forth quite a few times.

Journals are judged to some extent by their impact factor:

- Nature 38.138 (Science journal)
- Cell 28.710 (Science journal)
- Journal of Physical Chemistry A 2.8 (Engineering)
- Physical Review B 3.7 (Engineering)
- IEEE Journal of Quantum Electronics 1.8 (Engineering)
- Ideally you want to put your paper somewhere where it will be read by people in your field.







The cover letter



• With the paper you usually need to write a cover letter



College of Electronic Science and Engineering Jilin University Changchun 130012 P. R. China e-mail: <u>sp. wen@ilu.edu.cn</u>

12th September 2016

Dear Editors,

We would very grateful if you could consider the attached manuscript "Combining <u>Plasmonic</u> Trap Filling and Optical <u>Backscattering</u> for High Efficiency Third Generation Solar Cells", for publication in Energy and Environmental Science.

High efficiency third generation solar cell, often use transparent metal oxide contacts such as those made form Π_{QX} . It is common to light soak these layers using high energy (UV) light, this significantly increases device efficiency by generating hot charge carriers, which fill trap stats in the oxide layer. However, UV is well known to degrade both organic and inorganic materials, and thus this process is not compatible with the search for longer device lifetimes.

In this manuscript, we demonstrate the general result, that by tuning the shortest side of metal <u>nano-particles</u> to generate hot charge carriers from visible light, then by embedding these <u>nano-particles</u> in the metal oxide contact layer of a solar cell; the benefits of UV light soaking can be gained from visible light alone. We then tune the longest dimension of the metal <u>nano-particles</u> to promote light trapping in the device. Using this general strategy, we demonstrate that a state-of-the-art <u>low-bandgap</u> thieno[3,4-b]thiophene/ benzodithiophene/ Phenyl-C70-butyric acid methyl ester (PTB 7:PCBM) cell, can have it's efficiency boosted from 7.91% to 9.36%.

- The cover letter should tell the editor why he should publish your paper.
- Why his readers will be interested in it.
- And why your paper will get cited and thus increase his journals impact factor.

Send the paper/letter to the journal



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Send the paper/letter to the journal



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- This process takes about a year+ from start to finish.
- Key to this process is **peer review**, where three experts in the field w paper on quality and nove
- It is not like a newspaper publish any old rubbish

Engineering Ultra Electronic Device

College of Electronic Science and Engineering

Combining Plasmonic Trap Filling and Optical Backscattering for Highly

Efficiency Third Generation Solar Cells Chen Ydagi, Jajan Gogi, Shangang Ydai,* Pengfei Mei, Roderick C. I. MacKenzie

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organic solar cells (OSCs) to achieve better optical absorption without increasing the thickness o organic layer." It is well known that when integrated into OSCs, these metal party-particles can a

Shengping Step⁴

Abstract

7.91% to 9.36%

Dear Editors.

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rs do this for free so be nice to them!

Final words on papers



- They are a **very raw form of knowledge** and represent the **latest thinking in a field**.
- Information in papers may later be found out to be **wrong or indeed contradict other** ideas which were published later.
- So, you should always be critical of things written in papers and judge for your self if they are correct.



The process of knowledge dissemination



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Idea/New exciting data

• But papers are a very raw form of knolage, how is this distilled and refined.....

Refining knowledge..

- UNITED KINGDOM · CHINA · MALAYSIA
- After 10 years or so when lots of papers have been published in a given field and there has been a body of knowledge been generated.
- Somebody will write a book on the topic.



Academic books



- Often the contents of these early academic books, is mainly correct but there can be errors and mistakes in the filed.
- They should also be treated with caution.



 In general after about 10-15 years there will have been enough books written on a topic and enough papers published that we have a good idea of what is correct/not correct in a field.

Overview of the process, from paper to lecture.



The University of

Nottingham



• Time scales can vary, these are just to give you an idea.

Lecture outline



- The process of knowledge dissemination
- What's the point of references?
- Clarity of writing
- Good figures and graphs.
- How to write a scientific report
 - Abstract/Method/Discussion/Conclusion
- How to write a scientific paper.
 - Abstract/Introduction/Results/Discussion/Conclusion
- What editors look for in a paper.
- How to write a thesis



1 Introduction

Organic solar cells have recently shown great promises as a low cost source of low carbon electricity, their efficiencies have rapidly improved from 3% in 2007¹ to over 10% today.² There has been much work done on optimizing all aspects of organic photovoltaic devices (OPVs) including; development of narrow bandgap polymers to improve light absorption;³ developing better contacts^{4,5} to replace expensive Indium Tin Oxide;^{6,7} and development of faster production technologies to reduce the fabrication cost.^{8–10} However the cost per Watt of energy produced with an organic solar cell is still not competitive to silicon^{2,11} and for OPV devices to become commercially viable, improvements still need to be made in both efficiency and cost.

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Grounding everything you say to the literature.



1 Introduction

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- Can you see that every time I say something is true, I put a reference to back it up.
- If people don't believe what I am saying, then they can go and find the references to convince them selves.

• If they disagree with me, they not only have to disagree with me but also the author of the other paper.

• They also provide a jumping in point for people who are new to the subject.

References

- UNITED KINGDOM · CHINA · MALAYSIA
- Generally in science/engineering you are not allowed to make statements without a reference backing them up.
- For example you can not write,
 - "I think solar energy is the fastest growing form of energy"
- because that is what they do in the sun ->
- You must back it up with a reference. Solar energy is the fastest growing form of energy^[1]



Web references?



- Web references are bad, this is because your written work will be read by other long after you are dead.
- This means that in **200 years**, someone needs to be able to find the reference you are citing.

ON THE MOVEMENT OF SMALL PARTICLES SUSPENDED IN STATIONARY LIQUIDS REQUIRED BY THE MOLECULAR-KINETIC THEORY OF HEAT

by A. Einstein

[Annalen der Physik 17 (1905): 549-560]

 $F = -\frac{R}{N} T \lg \int e^{-\frac{EN}{RT}} dp_1 \dots dp_{\ell} = -\frac{RT}{N} \lg B.$

Let us now imagine a liquid enclosed in the volume V; let the partial volume V^* of V contain n dissociated molecules or suspended bodies, which are retained in the volume V^* by a semipermeable wall; this will affect the integration limits of the integral B entering the expressions for S and F. Let the total volume of the dissolved molecules or suspended bodies

¹In this section it is assumed that the reader is familiar with the author's papers on the foundations of thermodynamics (cf. Ann. d. Phys. 9 (1902): 417 and 11 (1903): 120). Knowledge of the papers cited and of this section of the present paper is not essential for the understanding of the present paper's results.



- There are lots of different forms of referencing, which should I use?:
 - (1) Emmott, C. J.; Urbina, A.; Nelson, J. Effects of Annealing and Degradation on Regioregular Polythiophene-Based Bulk Heterojunction Organic Photovoltaic Devices. *Sol. Energy Mater. Sol. Cells* **2012**, 97, 14–21.
 - [1] M. A. Green, K. Emery, Y. Hishikawa, W. Warta, and E. D. Dunlop, Prog. Photovolt: Res. Appl. 20, 12 (2012).
 - 14. Cabanillas-Gonzalez, J., Grancini, G. & Lanzani, G. Pump-probe spectroscopy in organic semiconductors: monitoring fundamental processes of relevance in optoelectronics. *Adv. Mater.* 23, 5468–5485 (2011).
- It does not matter at all, but do stick to one style!
- I suggest you use a reference manager, to do the hard work for you (See H14ERP).

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How to write scientific English



- Scientific English should use short sharp sentences which say exactly what you want to with the very minimum of words.
- An example of a bad sentence would be:



"To do the experiment we all got together in the lab on Tuesday and measured the waves in the wave tank many times."

A better example would be





Using a ripple tank (with an oscillator running at 10 Hz), the interference pattern was projected onto the desk (see diagram). We then used a ruler to measure the peak-to-peak distance which was found to be 1.5 cm.

• Notice every part of this sentence tells me new information, it is sharp, short and accurate.

Deadwood phrases



a majority of -- most

a sufficient amount of -- enough

according to our data -- we find

accordingly -- therefore, so

after the conclusion of -- after

along the lines of -- like

as is the case -- as is true

ascertain the location of -- find

at such time as -- when

at the present time -- now

at this point in time -- now

give consideration to -- consider, examine

give indication of -- show, indicate, suggest

happen(s) to be -- am/is/are

has been proved to be -- is

if conditions are such that -- if

in a number of -- several, many

in all cases -- always

in case -- if

in close proximity to -- near

in excess of -- more than

in the vicinity of -- near

in this case -- here

in view of the fact that -- because, since

is capable of -- can

is found to be -- is

is in a position to -- can

it has been found that -- (nothing)

it has long been known that -- (nothing)

it is a fact that -- (nothing)

it is evident that -- (nothing)

http://www.pnl.gov/ag/usage/deadwood.htm

Deadwood phrases



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prior to before	future predictions predictions	
provided that if	general rule rule	
put an end to end	green colored green	
reach a conclusion conclude	increase in increments increase	
serves the function of being is	initial prototype (model) prototype	
subsequent to after	joint cooperation cooperation	
the question as to whether there can be little doubt that	major breakthrough breakthrough	
probably utilize or utilization use	modern science of today modern science	
with reference to about	most optimum optimum	
with the exception that except that	necessary requirement requirement	
Your go!





- Describe this experiment in as few words as possible.
- Then discuss this with your partner.
- We will read these out a bit later.

https://www.youtube.com/watch?v=p4Mq1B1-XO w



- Finally, in English, when you write Science and Engineering documents.
- Don't try to show the reader how clever you are by using long words, or fancy language, just keep every sentence to the very minimum.
- Try to **avoid acronyms** (**TLAs!**) they just make stuff much harder to understand.
- Always, try to write as if you are trying to explain what you are doing to a **clever child.**

Lecture outline



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• What's this about?

Tom (named "Jasper" in his debut appearance) is a grey and white domestic shorthair cat. ("Tom" is a generic name for a male cat.) He is usually but not always, portrayed as living a comfortable, or even pampered life, while Jerry (named "Jinx" in his debut appearance) is a small, brown, house mouse who always lives in close proximity to Tom. Despite being very energetic, determined and much larger, Tom is no match for Jerry's wits. Jerry also possesses surprising strength for his size, approximately the equivalent of Tom's, lifting items such as anvils with relative ease and withstanding considerable impacts. Although cats typically chase mice to consume them, it is quite rare for Tom to actually try to consume Jerry. Most of his attempts are just to torment or humiliate Jerry, sometimes in revenge, and sometimes to obtain a reward from a human for catching Jerry. By the final "fade-out" of each cartoon, Jerry usually emerges triumphant, while Tom is shown as the loser.

However, other results may be reached. On rare occasions, Tom triumphs, usually when Jerry becomes the aggressor or when he pushes Tom a little too far. In *The Million Dollar Cat* Jerry learns that Tom will lose his newly acquired wealth if he harms any animal, "including a mouse;" he then torments Tom a little too much until he retaliates. In *Timid Tabby* Tom's look-alike cousin pushes Jerry over the edge. Occasionally and usually ironically, they both lose, usually when Jerry's final trap or attack on Tom backfires or Jerry overlooks something. In Chuck Jones' *Filet Meow*, Jerry orders a shark from the pet store to scare Tom away from eating a goldfish, but finds himself entirely intimidated as well. Finally, they occasionally end up being friends, although within this set of stories, there is often a last minute event that ruins the truce. One story that has friendly ending is *Snowbody Loves Me*.



• Don't know and it' looks quite boring...



- What's this about?
- What's happening?



- What's this about?
- What's happening?

• All we need to understand what is going on is good pictures/figures and a little bit of text or figure captions.

Good figures and graphs





Think of a paper or a report as a cartoon. Can you understand it by looking at the figures alone.



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Muhriels .			INTEGP			Animoto Animot	
Extracting Microscopic Device Parameters from Transient Photocurrent Measurements of P3HT:PCBM Solar Cells Rederick C. 1. MacKensie, * Christopher G. Shuttle, Michael L Chabinyc.					FULL PAPER	this can be shown as analogues to a Largevin recombination model which includes currer raps? ¹⁷ Abhough as responsibil Dod was useful to explain recom- bination, for exact status of the Dodi in OW materials in any could be described by two Gamesian control associated boxen succession dissider withial (USMS) and the higher coursed analocial working (MOD). ¹⁸ However, it was	 The Model To malei the electrical response rise transport across the device is energy space must be across drift definitions result is used 1 predices space, and at each 1 multi exergy space hereares
and Jenny Nelson				~		observed that a Gaussian Dod can not explain the polaron decay	discretized to provide map leve takes place. The model is desc
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By including trap-limited recentlination in a time-domain deft-diffusion model of a PHTPACIM value cell, reperimental transition photocorress (IPAC) measurements accords the correst-obage ()/correst in blot the light and the dark can be expected. Using the same set of model parameters, the mady-state curved-obage correst and ch arge-extension data are also			within the devices. Understanding of these physical processes in complicated by the inherest electronic and structural de- ender in these modecular material systems. Structural and energetic disorder leads to a distribution in the energetic states wouldn't or photogenerated electrons and			tial was found more appropriate. For a P.BHTPCEM solar cell it was found that only an exponential DoS could reproduce the photomoductivity spectra. ¹⁰⁴ and an exponential DoS has also been shown executial in reproduce convext-traking charge extraction data and resumbination data of this material with a defit difficience device model. ²¹⁷ Downite the summer: there is the achieventical model addet	To model free carrier transpor- medium approximation is use layer in considered. ^{19,10} To ab the device Poissnatic equation (
reproduced. The model is validated by predicting the recombination rate at open circuit and comparing results with the rate as measured by the tran- siont photovoltage (TPV) measurement technique. It is demonstrated that the model, which incorporates transport, carrier responder, carrier de trapping.			boles. The exact shape of this density of states (DoS) is important in determining the material/ electronic properties but is not known? ⁻⁹ Undentanding both the Ded and the wrombination revolutions.			can self consistently describe an OPV device in both steady state and for away from equilibrium number transient conditions. The masses for this lack of a model is that there is no concensus on the shape of the DoS and the way in which charges are trapped	$\frac{d}{dx} \cdot e_k e_k \frac{dy}{dx} = \phi(n - y)$ between the transparent from the desired of $(e = \phi)$, where e_k is the
and recombination, is able to reproduce device dynamics correctly. The fit of the model to the experimental results is improved by varying the shape of the electron and hele density of state (DoS) functions. By disordizing the DoS is measure more and advance in shape to your the two the fit resultants can be			in OPTs is essential if efficiencies are to be increased to sommercially visible levels. Recently, inside into the form of the			and referred from tail stores. To determine this both, strady state and transient experimental data are required. In this work we demonstrate that the Shackley-Read-Hall model can describe both the strady state and transient behavior of an OPV	the readily permanance or r tary charge on an electron. If fons are denoted by n and p : fixes within the device the electronic
Course the second secon		Du5 for poly 3-hosylthiophenephenyl-G53- butyrk acid methol enter #78/TEPG8M) has been gained by analysis of the charge density dependence of recombination. ²¹			device. Further suggesting that the fire-to-trap recombination mechanism is a good description of recombination in organic solar cells. To achieve this we present a transient vention of the device model and calibrate it against transient photocurrent TTPD, the source second of another abuncas is the deviced in	$\frac{\lambda f_n}{\partial x} = q \Big[R_n - G = \frac{\lambda m}{2 \delta} \Big],$	
stronuces by morecular packing of the	monta es.		is charge extraction (CI) and Varsient photomiage (TI'i) have been used to gain			the light. TPC transients are produced by applying a light and voltage bias to a solar cell under load, then subjecting the cell	$\frac{\lambda f_s}{\lambda r} = -q \left[R_r - G + \frac{\lambda p}{2r}\right]$
1. Introduction experimental to managemental to programmental to programmenta to prog		ght interrecentionation mechanisms." These reverse that the two operationate recention- over-law dependence on carrier density and else, where $s \rightarrow 3$ and it in the reduced Langevin on constant. ¹¹ (2) It has been demonstrated an expenential density of trapped white and dependent mobility into the Langevin meson: $t \approx 1$ (a) pp. 4 where $R \approx 10$, pp. 7 the power.			to a donce optical plane, the second general standard term is more smoothly conversion transport, recogning, deveraping, and recombi- nation and is prototalized a sile, names of device information all of these processes. Unit low PIC has been language significant because it is hand to securat information from these complex transients. However, the present model incorporates all these effects and therefore allows TPC transients to be interpreted for model can specific the hand proceedings of TPC transients for a resp.	are solved where J is the ch the hole flux density, K_{ch} are the face carrier generation or promensum cancertain or $\mu^{(1,1)}$	
nanport ²⁰ recombination. ^(n.4) and col	lector mechanisms	law dependence understood. We l	of recombination on cattler density can be save shown that by using this recombination is module on othe to self-constraints mean			 from the calibration voltage and can also reproduce measured recombination rates at open circuit, suggesting recombination is bring second-black. 	$f_{a} = \frac{1}{2\pi} \frac{1}{2\pi} + \frac{1}{2\pi} \frac{1}{2\pi} \frac{1}{2\pi}$ and for holes as
Oc. R. C. I. MacKenzie, Prof. J. Nelson Department of Physics Impenal College Landon		duce the steady tion, and recently Provious works w	an major are any to led consistently repri- tate experimental J-V corver, charge extra- ination data in both the light and the dark. ⁹¹ hich used the assumption of parabolic hands			In agreement with previous work we find that an exponen- tial De5 can generally reproduce both the study state and tran- sient electrical data. ^[217] However, we observe that at long time	$\label{eq:jg} \begin{split} j_{\theta} &= q\mu_{0}p\frac{\partial\xi_{0}}{\partial x} - q\Omega_{0}\frac{\partialp}{\partial x},\\ \text{for the free carrient we as} \end{split}$
den, DIY 282, DX att createstingtimperatal.sk R.C. 1 Machinese, Huf. J. Nelson AS, School of Saft Matter Research westy of finishing entities (307936) Restlung, Germany 5. Shottle (307936) Restlung, Germany 5. Shottle, (307936) Restlung, Germany 5. Shottle, (307936)		without traje we however, they we the recombination within these dev (SRI) recombina relat cells and p In OPVs SIII re- ducing sharps en-	be and to reproduce device j=V convergences or malde to conjulia the carrier dependence of a rate rear the large charge demittes abserved locs ^[24,17] . Recently, the Shockley-Eash-Hall rists model has also been replied to cogatie dyner light emitting docks (FEEbs) ^[26,102] emittation has been shown capable of repro- tations, j=V ₀ and recombination data, while			solar the TPC transient devide trues an ideal ranse orpeoers, til deva, by memorically primiting the shape of new Dod to reproduce the east shape of the TPC signal, we can extract both the 193000 and ULMOD Def form the TPC transients. This method provide insight into the shape of the Dod ar- comptor for lawer than addressible by replical methods alone. ^[20] B is found that the Dod between the 10000 and ULMO com- tories of a source of four intermet of first in earning the methods.	tes, I_i and I_i define the feo defined as $I_i = -\chi - \phi$ and . E-more between the LUMD level and I_i is the difference multility edge. 22. Transier Detropolet and
University of California Santa Barbara Santa Barbara CA 90106-3058, USA		in PLEDs it has I tion at low light	even sharen to dominate Langevin recombina- intensities. ⁷⁴ The SRH recombination model			that each of these energetic tup levels is caused by the P501T and DTDM melocoles in different tracks) and thus consection	To departure coming interaction
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washing par.



- And let's face it what you write will be pretty dull so people are not going to read the text anyway :)
- Communicate through pictures

Always assume this!

• Examples of good and bad graphs/figures...





Examples of wonderful figures.



FIG. 8. (Color online) Normalized modal profiles of the probe light for photon energies of 2.3 (blue), 2.6 (green), and 3.0 eV (red). It can be seen that as photon energy is increased the photon density on the left-hand side of the device increases. Thus at low photon energies the EA measurement will only be sensitive to band bending on the right-hand side of the device, while at higher photon energies, the EA measurement will be able to measure average band bending over the whole device.



FIG. 9. (Color online) The average carrier density corresponding to free (hot) and trapped (cool) electrons during the measurement. Initially all photogenerated carriers are free but as they cool they become trapped. It can be seen that during the first 10 ps there are more free carriers than trapped carriers; this is the reason for the initial fast separation of the charge packets. It can be seen that past 10 ps most carriers are trapped and thus do not move; this is the reason for the second slow phase to the charge separation transient. At long times the number of trapped carriers decreases; this is due to recombination.



Is this a good or a bad figure?



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ComRes UK poll, fieldwork 29-31 May 2009



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• Remember you are trying to communicate a message to the

reader





Voting intentions of major UK political parties: May 2005 - March 2010

• What has the author done to make the figure more clear?



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What is missing on this graph?



The University of Nottingham

The Oil Age World Oil Production 1859 - 2050

Oil was created from the remains of plants and oil bound body core millions of years. The source of mart ing tome 90 and 150 million years ago, and to the shallow teas thereing with digge last covered much of the each at the time. As generation of sea ifs stifted to the bottom, a unique caboorich satismerrary rock was formed. Over time, some of the rock stark

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and 1979 oil shocks. Oil is finite and non-renewable. Of the earth's total endow-ment of conventional crude, we've consumed about half so far. New discourtes of all pecked in the mid-1960s and by the early 1980b, we began consuming more all than we found. Today experts say we consume about four to six barrels of all for each one discoursed. Meanwhile Bows from therequarters of the

world's largest al-producing countries have already topped out and are shrinking year by year'. These trends point to a cress-roads that draws closer every days. The point and decline of global al production. American geophysicia Marian King Hubbert was the first to analyze the phenomenan d⁴ peck al.⁴ Decades ago the observed low all production-whether in a fail or region-method to Slow

new an production—whether in a field or region—whether to bollow a bell curve, niting steadily in the early years, then sowing as the most productive wells played out and new drilling failed to catch up. The peak, he found, occurred near the midpeint, when about half of the deposits had been extracted. In 1956, Hubbert deve on these observations to correctly predict the 1970 peak in U.S. antichum anotytics.

petroleum production. When will the world's oil flows crest? Estimates vary, but a growing number of expetits believe the provide standard voir go the growing number of expetits believe the pack is at hand. One prominent geologist, Calin Campbell, whose projections are diplayed on this poster, says global oil production likely posked in 2008. Other forecasts place the pack somewhere between 2005 and 2025. By dimost any massure, we are within a few years of entring the second half of the Cil Age—on era marked by see-

entreing the second half of the CJI Age-on era marked by ver-helding supplies of man's not precision controlly. Is the world ready, for park all "One influential report the world ready, for park all "One influential report development of the parks to avail anger disputchin," for industral societies that depend on all for everything from transportation and, latering to mandrularity and the source of the system or Whether we can develop substitute source every of the substitute our way of like is a question that laters larger every day.



The Power of Oil

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Production and Consumption World Oil Reserves ortation 1.55% of all goes to power the -Oil Producers is solicou of bonsh per day, 2009 Oil Cons Roughy 70% of electrical power in the 0.5, come from fossil fuels—including coal (49%), natural go (20%) and al (1.6%)—with nuclear (19.4%), hydre electric (7.0%) and other reservables (3.1%) makin up most of the rest. Oil distillates such as kerosen a yields roughly 30 Ton Oil Export Too Cil Importers 2 4 6 8 10 12

The Growing Gap"

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Oil's Cousins: Coal and Natural Gas

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UNCONVENTIONAL OIL

Natural Gas Liquids

Polar

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No phony of 40 A (24 Age would be contain which strips in scores if is strip and the strip in score is a strip and the strip in score is strip and

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os and liquid fuels, making it a p r al.¹⁸ Yet it is the dirtiest of the il, natural gas has in limits. Discovery ad in the 1970s and by the 1990s, if



2020



Surface Charts: come in handy if you are to determine the optimum combination

between two sets of data.



Electoral Prediction Map

Which candidate will win each state and reach 270 electoral votes first? Hover your mouse over the states to see the number of electoral votes.

Total number of Electoral College votes: **538** Total needed to win: **270**



Based on data from CNN.com the morning of November 5, 2012, using SAS/GRAPH software

You should think of every figure as a work of art.

Lecture outline



- The process of knowledge dissemination
- What's the point of references
- Clarity of writing
- Good figures and graphs.
- How to write a scientific paper.
- How to write a scientific report
- How to write a thesis.
- How to write a literature review.

Rule 1: Short is good

ConsMar

being extracted from the organic semiconductor divided by the current due to the geometric capacitance of the device; and t_{max} is the time at which the maximum current is observed in the transient. A typical CELDV transient is depicted in Figure 1. In the derivation of Eq. (1), Justa described the most mobile currier species as a uniform sheet exclude the most mobile currier species as a uniform sheet

of charge of carrier density n (m-3), which extends acros

the device. As the voltage ramp is applied, Juska describes this charge sheet being uniformly swept to the extracting contact leaving a region of length l(s), depleted of charge

contact leaving a region of length (U), depleted of charge behind it. Juska assumed hund like transport, neglecting the presence of traps. Today, however, it is well known that up to 90% of charge in a working organic solar cells resides in deep trap states;^{1,13} and the deeper the tap the longer it will lake for a carrier to be relaxed. Thus, rather than a well defined sheet of charge being swept out of the device, it is

far more likely that the charge sheet will become spread out

and distorted by carrier trapping and escape events

Therefore, it may not be possible to neglect carriers traps in

the derivation of the CELIV method. Furthermore, Juska

bility. However, today it is well known that the mobility is a

billy. However, lockay it is well known that the mobility is a stoog function of carrier density and in turn carrier density is known to be a stoog function of applied voltage.¹⁴ thus the mobility of the material well (change as the CELUV vol-age ramp is applied to the device to estract the carriers. The relationship between mobility within a device and potential applied to it can be described by the equation,

where $\mu_{e,h}^0$ is the mobility of free carriers, $n_{e,h}^{free}$ is the density

where $p_{c,h}$ is the innotativy of increasing $n_{c,h}$ is the density of free carriers, $n_{c,h}^{comp,h}$ is the density of trapped carriers, V is the applied voltage, and d is the device fluctures; this equation explicitly states that the mobility of trapped carriers is

 $n_{c;h}^{facc}(x, V)$

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 $\mu_{r/h} = \frac{1}{d} \int_{0}^{d} \mu_{r/h}^{0} \frac{n_{r/h}^{r}(x, V)}{n_{r/h}^{free}(x, V) + n_{r/h}^{rapped}(x, V)} dx, \quad (2)$

med that the material had one constant free carrier me



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orders of magnitude. We demenstrate that the change in TELIV transient upon aging can be explained by Ac. --in of trap states.

ANTS K. BINOY, Y. Hohikova, W. Wata, and E. D. Daulop, Prog. 20(1), 12–23 (2007).

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⁹R. C. I. MacKente, C. G. Shutle, G. P. Dills, N. Treat, E. von Haull, M. Sabi, C. J. Hardaw, M. L. Chabaya, and J. Nalasa, J. Phys. Cham. 1975(2), 1982–1991.

APPLIED PHY SICS LETTERS 103.063904 (2013)

The physical meaning of charge extraction by linearly increasing voltage transients from organic solar cells

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(Received 3 May 2013: accented 24 July 2013: published online 9 August 2013)

Carrier mobility in organic solar cells is almost exclusively determined with the Charge Carrier mobility in organic solar cells is abnot exclusively determined with the Charge Entration by Linearing broken pice (EU) vice hange, include on tack of our analysis of the second-handin and charge transport mechanisms in organic solar cells is hand on CELW organic estimations that and the entransport of the second second second second organic estimations that significantly advanced. In this work, we critically examine the CELW methods ability to provide accurate material data in the light of recent advances in our materialized or any attense of the index of the distribution of the second second second second second section 2003 AMP methods and the mechanism responsible for degradation in organic solar cells. 2003 AMP methods and the mechanism responsible for degradation in organic solar cells. 2003 AMP methods and the mechanism responsible for degradation in organic solar cells. 2003 AMP methods and the mechanism responsible for degradation in organic solar cells. 2003 AMP methods and the analysis of the distribution of the distribution.

Organic solar cells offer the potential of a low-cost,¹ low-carbon source of electricity. Within the last five years, power conversion of ficiencies have increased from 3%² to over 10%³ today. However, to further increase energy conversion efficiencies, a larger proportion of the photogener-ated charge carriers need to reach the contacts of the cell.⁴ To achieve this, the lifetime (τ) and the mobility (μ) of the naterials charge carriers must be maximized.4 Researchers often use the Charge Extraction by Linearly Increasing Voltage (CELIV)⁵⁶ method to measure mobility⁷³ within oftage (CELIV)³ method to measure mohtig³ within search devices to guide both devices and material develop-err. However, since Jacks²⁶ first pioneered the CELIV fields our understanding of organic exenic enductors has ansiderably improved.²¹⁶ In particular, our understanding (Catage tanapene): In this letter, we examine the underlying exercical assumptions made by AsiaSia⁶ in the derivation of the CELIV measurement technique and hold them up to crutiny against today's knowledge of organic semiconduc tor materials.7 The ability to accurately measure mobility in anic semiconductors is essential if the material system used in organic solar cells are to continue to be developed In Juska's original paper, he derived the now we we equation to extract mobility from CELIV transients,

> d^2 $\mu = \frac{2}{3} \frac{d^4}{A t_{max}^2 \left(1 + 0.36 \frac{\Delta j}{j(0)}\right)}$

where, A describes the ramp rate (V/s) of a negative triangu lar voltage function applied to the cell; this voltage ram isially starts at around 0V and decreases to typically -1V -5 V of applied bias within 10-20us; d is the thickness o levice: Ai/i(0) is the ratio of the current due to chara

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pemittivity of the medium, $n_{ev}(p_{ev})$ is the sum of the free and trapped electron (hole) population. To simulate the movement of free carrier, the because where $\mu_e(\mu_A)$ is the free electron (hole) mobility, E (E_{NOMO}) is the spatially dependent potential of the LUMO (HOMO), $D_{\kappa}~(D_{\mu})$ are the electron (hole) diffusion coeffiients. Conservation of narticles is forced usine the carrie

ell aged for 1176 h using a UT 5 °C with a relative based of

ro. Thus, we must ask if the mobility of the material in the device is changing during the measurement, how does this effect our value of mobility as measured by the CELIV method?

where N²⁰ are the detunnable top datability at the LLDSD and LLDSD edge ($Z^{\rm eff}_{\rm eff}$ and the American elevation has an and HDMSD edge ($Z^{\rm eff}_{\rm eff}$ and the American elevation has a straight of the American elevation elevation of the American elevation elevation of the American elevation elevation elevation of the American elevation el Finally, the CELIV method was derived for a material system where one material had a very low mobility and the other carrier species had a high mobility. However, due to mproved polymers,15 today's high efficiency devices have sore balanced mobilities and it is thus not clear that one carier remains immobile and thus CELIV theory holds. In the riter remains immostue and thus CELIV theory notis, in the following pages, we address these questions using a combi-nation of experimentation and theory; the result is a better understanding of how CELIV transients can be interpreted. Inverted bulk-heterojunction devices were fabricated with Inverse black heteropaction arvives were tables and volt of CoVAPCPHPTCHNWERDDTTSNAW and interture.¹⁰ Pho() the sylbiophene 2.5 dy() (1911) and phon) (XL) hyperic acid mody doer (CRM) were motion at weight as the other synthesis and the synthe Seen that an increase in the density of carrier scap states not only increases the magnitude of the CELUV peak, but also shifts the CELUV peak to the right. If one uses Eq. (1) to extract the mobilities, we obtain values of 1.1×10^{-2} to $3.0 \times 10^{-9} \, {\rm m^2 V^{-1} \, s^{-1}}$. Thus, we can determine from this

before the cell is aged is obtained, and a decreased mobility of $2.3 \times 10^{-9} \text{ m}^2 \text{ V}^{-1} \text{ s}^{-1}$ after aging is obtained. Be fore attempting to understand the change in measured

 $\frac{d}{dx} \cdot \epsilon_0 \epsilon_r \frac{d\phi}{dx} = q(n_{tor} - p_{tor}),$

mobility upon degradation, we first use our device model to better understand the physical mechanisms which can alto anisms which can alte CELIV transients. To model CELIV transients from an or ganic solar cell, we use an effective medium approximation where the LUMO level of the fullerene is taken as the electran mobility edge and the HOMO level of the polymer is taken as the hole mobility edge. To calculate the electric field profile within the device, Poisson's equation is solved in one dimensional

063904-3 Hanfland et al.

Appl. Phys. Lett. 103, 063904 (2013)

the bi-polar drift diffu

 $J_{\pi} = q \mu_c \pi \frac{\partial E_{LUMO}}{\partial x} + q D_{\pi} \frac{\partial \pi}{\partial x}$

 $J_{p} = q \mu_{h} p \frac{\partial E_{HOMO}}{\partial q} - q D_{p} \frac{\partial l}{\partial q}$

where N^{c/k} are the electron/hole tran densities at the LUMO

eraph that CELIV is measuring an averaged carrier m ty (as described by Eq. (2)), which includes the influence of carrier trap states. As was discussed above, carrier mobility in organi

As we as the sum of the second secon

ment of mobility is the CELIV method in general? To anere set equal and varied together from $\mu_{i}^{0} = \mu_{i}^{0} = 1 \times 10$ to 1 × 10⁻⁴ m² V⁻¹ s⁻¹. Equation (1) was used to extract the bilities from the CELIV transients and Eq. (2) used to tract the effective mobility from the model before the CELIV transient started. This was repeated for energetic tail slope energies of 5 meV, 25 meV, 50 meV, and 100 meV. Figure 4 plots the results. The black line is a guide to the Figure 4 pixels the weaks. The black line is a guide to the exactly the effective device modelly as given by Eq. (2, 3). The effective device modelly as given by Eq. (2, 3), modelly as extracted from the CHLV removes in which an outdoor of magnetized of the average device modelly. As sum-ond of magnetized of the average device modelly, set sum of the device of the average device modelly. As more index of sum devices the device by modelly devices device halo the draw of the device of modelly devices devices devices devices are sum of the device of the device devices devices defined in devices of the device device devices devices devices defined devices devices devices device devices devices devices defined devices devices devices devices devices devices devices on the device devices dev ed from the device faster than carriers in deep



Appl. Phys. Lett. 103, 053904 (2013)



Device mobility calculated with Eq. (2) (of from the CELIV transients for did ed mobility was calculated after Deuber¹⁰ worn that CELIV can estimate mobility to

(see right hand side of Figure 5); this is because during the application of the CELIV voltage ramp the quasi-lerma izer-el(s) of the fire carriers will progressively move to lower energies loxing ever more deeply rapped states to release their carriers in order to move towards equilibrium, further-more shallowly trapped carriers take less time to thermatice all become mobile than carriers in the deept traps. Thus afther than a single uniform charge sheet being removed from the device, charge is removed progressively from deeper and deener trans across the entire device. Th sheet (and region l(x)) in the CELIV dori





 People are not that interested in what you have to say, so don't waste their time by writing too much.

N^{ah}=3x10²⁰ m ³ eV N^{ah}=5x10²⁰ m ³ eV N^{ah}=5x10²⁰ m ³ eV

- Always assume they have better things to do than to read your work.
- Keep it short and to the point.

063904-2 Harfland et al

ecombination we use the Shockley-Read-Hall model.18 The arrier traps are defined as an exponential distribution of $\rho^{r/h}(E) = N^{r/h} \exp(-E/E^{r/h}).$

The abstract



The physical meaning of charge extraction by linearly increasing voltage transients from organic solar cells

Robert Hanfland, ^{1,2,3} Martin A. Fischer,¹ Wolfgang Brütting,² Uli Würfel, ^{1,4} and Roderick C. I. MacKenzie^{3,5,a)}

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 ³FRIAS, University of Freiburg, Albertstr. 19, 79104 Freiburg, Germany
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 ⁵Faculty of Engineering, University of Nottingham, Notting ham NG7 2RD, United Kingdom

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Carrier mobility in organic solar cells is almost exclusively determined with the Charge Extraction by Linearly Increasing Voltage (CELIV) technique; indeed much of our understanding of the recombination and charge transport mechanisms in organic solar cells is based on CELIV measurements. However, since the conception of the CELIV method, our understanding of organic semiconductors has significantly advanced. In this work, we critically examine the CELIV methods ability to provide accurate material data in the light of recent advances in our understanding of trap states and their influence on mobility in organic semiconductors. We then apply this knowledge to understand the mechanisms responsible for degradation in organic solar cells. © 2013 AIP Publishing LLC. [http://dx.doi.org/10.1063/1.4818267]



- Keep the abstract short.
- 200-300 words.
- It should be about the level of a first year undergraduate course so almost anyone can understand what is in the paper.
- It should outline the key findings.
- Not too technical.

https://www.youtube.com/watch?v=ys8wHUPd6Vo&t=905

The introduction: Paragraph 1

Organic solar cells offer the potential of a low-cost,¹ low-carbon source of electricity. Within the last five years, power conversion efficiencies have increased from $3\%^2$ to over 10%³ today. However, to further increase energy conversion efficiencies, a larger proportion of the photogenerated charge carriers need to reach the contacts of the cell.⁴ To achieve this, the lifetime (τ) and the mobility (μ) of the materials charge carriers must be maximized.⁴ Researchers often use the Charge Extraction by Linearly Increasing Voltage (CELIV)^{5,6} method to measure mobility^{7,8} within research devices to guide both device and material development. However, since Juska^{5,6} first pioneered the CELIV method, our understanding of organic semiconductors has considerably improved.9,10 In particular, our understanding of charge transport in these material systems has considerably developed.¹¹ In this letter, we examine the underlying theoretical assumptions made by Juska⁶ in the derivation of the CELIV measurement technique and hold them up to scrutiny against today's knowledge of organic semiconductor materials.⁹ The ability to accurately measure mobility in organic semiconductors is essential if the material systems used in organic solar cells are to continue to be developed.

In Juska's⁵ original paper, he derived the now well known equation to extract mobility from CELIV transients,

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- Accessible to everyone, and should outline the problem in very general terms.
- Why care about solar cells?
- Why should I care about what you are writing about?

The introduction: Paragraph 2

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 Introduce the general problem/area that you are going to solve.

The introduction: Paragraph 3

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- Explain to an expert in the field why this is important.
- But still keep the language simple and to the point.
- Cite retentive literature.

The introduction



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 This section of the paper should be littered with references to show that you have read other peoples work and understand what you are talking about.

Experimental method (Or methods) section)



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- Describe what you did in the experimental method. •
- You must include enough detail so someone can repeat your experiment
- Here's the catch.... People don't like reading • experiential sections they are boring!
- So describe what you did in really brief terms. Maybe a paragraph or two.
- Then put the rest of the text in the supplementary • information (SI).



permittivity of the medium, $n_{ext}(n_{ext})$ is the and trapped electron (hole) population. T ment of free carriers, the bi-polar drift diff

$$J_{\mu} = q \mu_{e} n \frac{\partial E_{LDMO}}{\partial \chi} + q D_{\mu} \frac{\partial n}{\partial \chi},$$
 (4)
 $J_{\mu} = q \mu_{e} p \frac{\partial E_{ROMO}}{\partial \chi} - q D_{\mu} \frac{\partial p}{\partial \chi}.$ (5)

 $\rho^{r/h}(E) = N^{r/h} \exp(-E/E_{r}^{r/h})$

nd E is the distance from the LUMO/HOM

 (E_{HOMO}) is the spatially dependent potential of (HOMO), D_{α} (D_{μ}) are the electron (hole) diffic cients. Conservation of particles is forced using the tions and to describe carries tion we use the Shockley-Read-Hall model

and HOMO edge; $E_a^{r/3}$ when A full list of device parameters are given in the



The physical meaning of charge extraction by linearly increasing voltage transients from organic solar cells

Robert Hanfland^{1,2,3}, Martin A. Fischer¹, Wolfgang Brütting², Uli Würfel^{1,4}, and Roderick C. I. MacKenzie^{3,5a),} View Affiliations DOI: http://dx.doi.org/10.1063/1.4818267 PDF ABSTRACT FULL TEXT FIGURES SUPPLEMENTAL CITED BY TOOLS SHARE METRICS

Carrier mobility . Charge carriers . Solar cells . Organic semiconductors . Electric measurements

Results/Discussion



- Some people/journals like to separate out the results section and the discussion of the results section.
 - I don't.

APPLIED PHYSICS LETTERS 103.063904 (2013)

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(Received 3 May 2013; accepted 24 July 2013; published online 9 August 2013)

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rodetick mackenzie@nottintham.ac.uk 0003-6951/2013/103(6)/063904/4/\$30.00 being extracted from the organic semiconductor divided by being extracted from the organic semiconductor divided by the current due to the geometric capacitance of the device; and t_{max} is the time at which the maximum current is observed in the transient. A typical CELIV transient is depicted in Figure 1. In the derivation of Eq. (1), Juska described the most mobile carrier species as a uniform sheet described the most mobile carrier species as a uniform shee of charge of carrier density (m^{-3}) , which extends accord the device. As the voltage ramp is applied, Juska describe this charge sheet being uniformly awapt to the extracting contact leaving a region of length l(x), depleted of charge behind it. Juska assumed band like transport, neglecting th presence of traps. Today, however, it is well known that up to 90% of charge in a working organic solar cells resides in deep trap states: 12,13 and the deeper the tran the longer it will take for a carrier to be released. Thus, rather than a well defined sheet of charge being swept out of the device, it is defined sheet of charge being swept out of the device, it is far more likely that the charge sheet will become spread out and distorted by carrier targping and exage events. Therefore, it may note be possible to neglect carriers traps in the derivation of the CELUV method. Parthermore, Jaska assumed that the material had one constant for carrier mo-bility. However, aday it is well known that the mobility is a strong four description of the model in the mobility is a strong function of carrier density and in turn carrier density is known to be a strong function of applied voltage the mobility of the material will change as the CELIV volge ramp is applied to the device to extract the carriers. The ship between mobility within a device and potential ribed by the equation. $n_{c|h}^{facc}(x, V)$ $\mu_{e/h} = \frac{1}{d} \int_{0}^{d} \mu_{e/h}^{0} \frac{n_{e/h}^{forc}(x,V)}{n_{e/h}^{forc}(x,V) + n_{e/h}^{orogod}(x,V)} dx, \qquad (2)$ where μ_{ch}^0 is the mobility of free carriers, n_{ch}^{free} is the density of free carriers, $n_{e|h}^{targed}$ is the density of trapped carriers, V is the applied voltage, and d is the device thickness; this equation explicitly states that the mobility of trapped carriers is © 2013 AIP Publishing LLC

	Appl. Phys. Lett. 103, 063904
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	and trapped electron (hole) population. To simular movement of free carriers, the bi-polar drift diffusion tions are solved,
And the second s	$J_{\pi} = q \mu_{c} \pi \frac{\partial E_{LUMO}}{\partial x} + q D_{\kappa} \frac{\partial \pi}{\partial x},$
	$J_p = q \mu_h p \frac{\partial E_{BOMO}}{\partial x} - q D_p \frac{\partial p}{\partial x}$,
20 40 60 Time (us)	where $\mu_e(\mu_b)$ is the free electron (hole) mobility, $E_{(E_{BOHO})}$ is the spatially dependent potential of the LI (HOMO), $D(D)$ are the electron (hole) diffusion of
surements (a) a non-aged cell and (b) a source equivalent to exposure at 1 San at	cients. Conservation of particles is forced using the c conservation equations and to describe carrier trappin

ero. Thus, we must ask if the mobility of the material in t device is changing during the measurement, how does this effect our value of mobility as measured by the CELIV

Finally, the CELIV method was derived for a mate material had a very low mobility and th es had a high mobility. However, due 5 other carrier species had a high mobility. However, due to improved polynem," is body whigh efficiency devices has more balanced mobilities and it is thus not clear that once are three the strength of the strength of the strength of the intervention of the strength of the strength of the materianting of body calculation and noncy: the world is a heat intervention of the strength of the strength of the hose of the strength of the strength of the strength of cAUCAPHIT (CAUNTREDOFTSANS) and a strength of the hose of the strength of the strength of the strength of the hose of the strength of the strengt

of 1:0.67. The active and poly(3,4ne) poly(styrenesulfonate) (PEDOT:PSS) (90nm) la re deposited by spin coating. The metal grid was therma evaporated. Devices were annealed at 130°C for 10 min. Cell aging was performed using a UV source equivalent to expo-sure under AM 1.5G radiation at 45°C with a relative humidof 6% for 1176 h. The resulting CELIV transients before aging are plotted in Figure 1. By applying Eq. tal data, a mobility of 9.5 × 10⁻⁹ m² V⁻¹ e cell is aged is obtained, and a decreased mobili



deal CELIV

the CELIV transient upon

r. J. Rash, Y. Dvalenov, and C. Deshel, Proc. Rev. B 46, 1153

• I tend to merge the results/discussion into an interesting story.

Conclusions



- 1 Paragraph max
- Summarize the key results

In conclusion, we have applied a modern model and understanding of organic semiconductors in combination with experiments to evaluate a method of experimentally measuring mobility originally proposed by Juska. We concluded that; (a) carrier trap states change the shape of the CELIV transient significantly; (b) the CELIV measurement itself changes the average carrier mobility by up to 50%; (c) the mobility as measured by CELIV can provide a good estimate to the mobility of the most mobile charge carrier for ordered materials, however, for materials with a high density of trap states, the estimate may be less reliable. For typical organic solar cells the accuracy of CELIV is within one or/



mes ill defined and CELIV becomes less accurate. olar cells often have mobilities ranging from the CELIV transient upon aging can be explained by the for $0.1 \times 10^{-6} \text{ m}^2 \text{V}^{-1} \text{s}^{-1}$ and tail slopes from 30 meV mation of trap states. we would expect CELIV to be accurate to lers of magnitude. See the supple more detailed analysis of this precess.¹⁹ Also CELIV tends to measure the mobility of the most harge carrier and asymmetric mobilities do not

4-21 (2012). M. A. Gircen, K. Emery, Y. Hishikawa, and W. Wata, Prog. Photovoltain 8, 425–410 (2007). uble peak in the measured current above discussion, it is clear that both free can nobility and the density/distribution of trap states an Azimi, A. Senes, M. C. Scharber, K. Hingerl, and C. J. Brabec, Adv arameters in defining the shane of CELIV transients us back to the question of how to understand the Jaška, K. Ar data in Fig ures I(a) and I(b). To understand is is physically doing to our cell, the nu at the aging process is physically doing to our ceil, the nu-rical model was fit simultaneously to the CELIV transient in the non-degraded cell in Figure 1(a) and the light and k JV curves. To perform the fit, mobility, trap densities, slope energies were altered.⁴⁷ After the model was cal-ted you must add to the fit the need experimental data the d, we were able to fit the aged experimental data by ther adjusting the carrier trap densities, we can ther

re say during the aging process additional trap states an merated within the material (possibly due to the introduc stir, J. Rash, V. Dealoney, and C. Deibel. of water and oxygen) and although CELIV measur I. MacKenzie, T. Kirchastz, G. F. A. Dibb.

Appl. Phys. Lett. 103, 063904 (2013)

ders of magnitude. We demonstrate that the change i

We are grateful for access to the Universit Nottingham High Performance Computing Facility.

C. J. Binmott, A. Urbina, and J. Nelson, S.d. Br

A 206 171 2731-2736/200

• Keep it short, punchy, and tell the reader what you found out. Don't tell the reader again what you did.

These are not conclusions



- "All objectives were achieved" the reader does not care.
- "The work was a success" leave that up to the reader to decide.
- "We performed measurements on 100 solar cells" no one cares.
- "We had highly efficient devices" let the reader decide.

Finally, how much will people read of my paper/report?



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APPLIED PHYSICS LETTERS 103.063904 (2013)

The physical meaning of charge extraction by linearly increasing voltage ents from organic solar cells

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3 May 2013; accepted 24 July 2013; published online 9 August 2013)

Organic solar cells offer the potential of a low-cost,¹ low-carbon source of electricity. Within the last five years, power conversion of ficiencies have increased from 3%² so over 10%³ loday, However, to further increase energy conversion efficiencies, a larger proportion of the photogener-ated charge carriers need to reach the contacts of the cell.⁴ To achieve this, the lifetime (τ) and the mobility (μ) of the materials charge carriers must be maximized.4 Researchers often use the Charge Extraction by Linearly Increasing Voltage (CELIV)⁵⁶ method to measure mobility⁷³ within Voltage (CELU)⁻⁻ method to measure motivity⁻⁻ within seearch devices to guide both devices and material develop-ment. However, since Justa²⁶ first poneered the CELU method, our understanding of organic emicinductors has considerably improved.¹¹ In particular, our understanding of charge tampengies in these material systems has consider-ably developed.¹¹ In this letter, we examine the underlying therereical assumptions made by Auka²¹ in the drivation of the CELIV measurement technique and hold them up to scrutiny against today's knowledge of organic semiconduc tor materials." The ability to accurately measure mobility in zanic semiconductors is essential if the material system used in organic solar cells are to continue to be developed In Juska's original paper, he derived the now we we equation to extract mobility from CELIV transients, me II

 $\mu = \frac{2}{3} \frac{d^2}{At_{max}^2 \left(1 + 0.36 \frac{\Delta j}{j(0)}\right)}$

where, A describes the ramp rate (V/s) of a negative triangu lar voltage function applied to the cell; this voltage ram usually starts at around 0 V and decreases to typically -1 V -5 V of applied bias within 10-20 as; d is the thickness of the device: Ai/i(f) is the ratio of the current due to chara

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being extracted from the organic semiconductor divided by the current due to the geometric capacitance of the device; and t_{max} is the time at which the maximum current is observed in the transient. A typical CELIV transient is depicted in Figure 1. In the devication of Eq. (1), Janka described the most mobile carrier species as a uniform sheet of observe or net device and the special sector. of charge of carrier density n (m-3), which extends acros the device. As the voltage ramp is applied, Juska describes this charge sheet being uniformly swept to the extracting contact leaving a region of length l(s), depleted of charge contact leaving a region of kengh (1), depleted of charge behind it. Jaska assumed hand like transport, neglecting the presence of traps. Today, however, it is well known that up 109% of charge in a working organic sohar cells resides in deep trap states;^{1,13} and the deeper the tap the konger it will take for a carrier to be relaxed. Thus, rather than a well defined sheet of charge being swept out of the device, it is far more likely that the charge sheet will become spread out and distorted by carrier trapping and escape events Therefore, it may not be possible to neglect carriers traps in the derivation of the CELIV method. Furthermore, Juska med that the material had one constant free carrier me bility. However, today it is well known that the mobility is a bility. However, soday it is well known that the mobility is a strong function of carrier density and in turn carrier density is known to be a strong function of applied voltage.¹⁴ thus the mobility of the material will change as the CELUV vol-age ramp is applied to the device to extract the carriers. The relationship between mobility within a device and potential applied to it can be described by the equation,

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Appl. Phys. Lett. 103, 063904 (2013)

 $J_{\pi} = q \mu_e \pi \frac{\partial E_{LUMO}}{\partial x} + q D_e \frac{\partial \pi}{\partial x}$, $J_p = q \mu_h p \frac{\partial E_{HOMO}}{\partial x} - q D_p \frac{\partial p}{\partial h}$ (5)

 (E_{MORO}) is the spatially dependent potential of the LUMO (HOMO), D_{α} (D_{α}) are the electron (hole) diffusion coeffiients. Conservation of narticles is forced usine the carrie ecombination we use the Shockley-Read-Hall model.¹³ The arrier trans are defined arrier traps are defined as an exponential distribution of

 $\rho^{r/h}(E) = N^{r/h} \exp(-E/E^{r/h}).$ where $\lambda^{(n)}$ are the determinish term densities at the LUBM HIMM of the HIMM of the set $\lambda^{(n)}$ are the characteristic determinish the size composition of k in the distance from the LUMM(HIMM) and $\lambda^{(n)}$ and $\lambda^{(n)}$ are also be set. Characteristic distances in the symplectic distance is the set of the size of the set of the se where N^{c/k} are the electron/hole tran densities at the LUMO Seen that an increase in the density of carrier scap states not only increases the magnitude of the CELUV peak, but also shifts the CELUV peak to the right. If one uses Eq. (1) to extract the mobilities, we obtain values of 1.1×10^{-2} to $3.0 \times 10^{-9} \, {\rm m^2 V^{-1} \, s^{-1}}$. Thus, we can determine from this



063904-3 Hanfland et al.

graph that CELIV is measuring an averaged carrier mobil ty (as described by Eq. (2)), which includes the influence of carrier trap states. As was discussed above, carrier mobility in organic

As uses a discussed abox, curve mobility in equation microsolutors in horizon of a section of a section matrix of the section of the section

ment of mobility is the CELIV method in general? To an vere set equal and varied together from $\mu_{i}^{0} = \mu_{i}^{0} = 1 \times 10$ to 1 × 10⁻⁴ m² V⁻¹ s⁻¹. Equation (1) was used to extract the nobilities from the CELIV transients and Eq. (2) used to attract the effective mobility from the model before the CELIV transient started. This was repeated for energetic tail slope energies of 5 meV, 25 meV, 50 meV, and 100 meV. Figure 4 plots the results. The black line is a guide to the Figure a pixel the result. The black line it a galake to the pixel pixel pixel pixel (in the pixel where C. The row pixel (g. 1). It is a pixel pixel pixel (in the pixel pixel pixel pixel) and can be seen that for a very shallow tail depet (SueV), thus can be seen that for a very shallow tail depet (SueV), thus pixel pixe



(see right hand side of Figure 5); this is because during the application of the CELU voltage ramp the quasi-Femi lev-cl(s) of the fire carriers will progressively move to lower energies footing ever more deeply rapped states to release the' carriers in ender to move towards equilibrium, further-more shallowly trapped carriers take less time to thermalize and become mobile than carriers in theoper traps. Thus arther than a single uniform charge sheet being removed from the device, charge is removed progressively from deeper and deeper trans across the entire device. Thi



o orders of magnitude. We demonstrate that the change in CELIV transient upon aging can be explained by the filling tion of trap states. We are grateful for access to the University

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acted from the device faster than carriers in deeper tra

• I'm afraid usually that's it.

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 $\mu_{c/h} = \frac{1}{d} \int_{0}^{d} \mu_{c/h}^{0} \frac{n_{c/h}^{low}(x, V)}{n_{c/h}^{low}(x, V) + n_{c/h}^{owped}(x, V)} dx, \quad (2)$

where $\mu_{c|h}^0$ is the mobility of free carriers, $n_{c|h}^{free}$ is the density

where $\mu_{c,h}$ is the informity of mee carriers, $n_{c,h}$ is the density of free carriers, $n_{c,h}^{input}$ is the density of trapped carriers, V is the applied voltage, and d is the device thickness; this equa-tion explicitly states that the mobility of trapped carriers is

• So make sure these parts are really good.

 $\frac{d}{ds} \cdot \epsilon_0 \epsilon_r \frac{d\phi}{ds} = q(n_{tot} - p_{tot}),$

Lecture outline



- The process of knowledge dissemination
- What's the point of references
- Clarity of writing
- Good figures and graphs.
- How to write a scientific paper
- How to write a scientific report
- How to write a thesis.
- How to do a literature review.
- Abstract/Method/Discussion/Conclusion
 - Abstract/Introduction/Results/Discussion/Conclusios

Lab reports



Generally lab reports take the same form as a paper:

- Title
 - Obvious √
- Abstract
 - We have discussed this \bigvee
- Introduction
 - We have discussed this \checkmark
- Methods
 - This is what you did. i.e. your method used for doing the experiment

- Results V
 - We have discussed this
- Discussion \lor
 - We have discussed this
- Literature cited \vee
 - We have discussed this

- You do generally however have more space in a lab report and they are in general more relaxed. You don't necessarily have to use so many references
- They are generally under 10 pages long and in size 12 text with diagrams/pictures/equations.

Lecture outline



- The process of knowledge dissemination
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- How to write a scientific paper
- How to write a scientific report
- How to write a thesis
- How to do a literature review.



You guessed it the structure is pretty much the same:

- 1 page: Title
- 1 page: Abstract
- Chapter 1: Introduction
- Chapter 2+: Methods
- Chapter 3+: Results
- Chapter 4: **Discussion**
- Chapter 5: Conclusion

+ indicates that the chapter can span multiple chapters.

• So now you really know how to write any type of scientific document!

Your go



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- Write a mini paper with a few sentences in each section.
- With one figure.
- I will come around and give you feedback.
- This should only take 5 min.



https://www.youtube.com/watch?v=UtHM eeJUKdo

Lecture outline



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Literature review



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• This part of a paper can be though of as a mini literature review.

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The physical meaning of charge extraction by linearly increasing voltag transients from organic solar cells

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ier mobility in organic solar cells is almost exclusively determined with the Charge action by Linearly Increasing Voltage (CELIV) technique; indeed much of our understanding of the recombination and charge transport mechanisms in organic solar cells is based on CELIV seasurements. However, since the conception of the CELIV method, our understanding of rganic semiconductors has significantly advanced. In this work, we critically examine the CELIV whods ability to provide accurate material data in the light of recent advances in our nderstanding of trap states and their influence on mobility in ormanic semiconductors. We then trap states and meri innuence on nosenay in organic space index to understand the mechanisms responsible for degradation in organic solar ells. © 2013 AIP Publishing LLC. [http://dx.doi.org/10 063/1.4818267

2012/102/6/062204/4/820.00



zero. Thus, we must ask if the mobility of the material in the device is changing during the measurement, how does this effect our value of mobility as measured by the CELIV

Fourth, the CELW method was derived for a mortical potent when one material had a very low modely and the other carrier species had a high mobility. However, due to improved polymens," had buy's high efficiency devices have inter remains manufale and then CLW theory holds. In the Molecular gaps, we are denotes the equations must a combi-nation of experimentation and theory, the result is a better inter remains manufale and then CLW theory holds. In the Molecular gaps, we are denotes the equations must a combi-nation of experimentations and theory, the result is a better and the molecular theory of the start of the start molecular density of the start of the start of the start of the 10 Art. The start and a poly-(10 Arthous and arthous Finally, the CELIV method was derived for a material

evaporated. Devices were annealed at 130°C for 10min. Cell aging was performed using a UV source equivalent to expo-sure under AM 1.5 G radiation at 45°C with a relative humidy of 6% for 1176 h. The resulting CELIV transients befor nd after aging are plotted in Figure 1. By applying Eq. (1) to re experimental data, a mobility of $9.5 \times 10^{-9} \text{ m}^2 \text{ V}^{-1} \text{ s}^{-1}$ before the cell is aged is obtained, and a decreased mobility of $2.3 \times 10^{-9} \text{ m}^2 \text{ V}^{-1} \text{ s}^{-1}$ after a ging is obtained. Be fore attempting to understand the change in measured

nobility upon degradation, we first use our device model o better understand the physical mechanisms which can alte CELIV transients. To model CELIV transients from an o e hole mobility edge. To calculate th

ice, Poisson's equation is solv $\frac{d}{d_{tr}} \cdot \epsilon_0 \epsilon_r \frac{d\phi}{d_{tr}} = q(n_{tor} - p_{tot}),$



where so is the permittivity of free space, c is the relativ permittivity of the medium, $n_{eee}(p_{nw})$ is the sum of th and trapped electron (hole) population. To simular sent of free carriers, the bi-polar drift diff



 (E_{BORD}) is the spatially dependent potential of the LUNO (HOMO), D_s , (D_s) are the electron (hole) diffusion coefficients. Conservation of particles is forced using the carrier conservation of quarticles is forced using the carrier trapping and to describe carrier trapping and combination we use the Shockey-Read-Hall model.¹¹ The carrier traps are defined as an exponential distribution of views.

 $\rho^{r/h}(E) = N^{r/h} \exp(-E/E_{r}^{r/h}).$ where Nr/h are the electron/hole trap densities at the LUMO

where $N^{(2)}$ are the electrony/hok trap densities at the LUMO and HOMO object. $E_{i}^{(3)}$ are the characteristic electron/hok tail slope energies and E is the distance from the LUMO/HOMO objec. A full fast of device parameters are given in the supple-mentary information.²⁰ parameters were chosen to be symmet-ric and us be close to those already speriord in the literature.² If Eq. (1) is a measure of free carrier mobility as

described by Juska in his derivation, then the density of carrier traps should not affect the shape of the CELIV tran-sient. To test Juska's approximation, Figure 2 plots five simulated CELIV transients with all device narameter held constant excent for the carrier trap densities. It can b seen that an increase in the density of carrier trap states no only increases the magnitude of the CELIV neak, but also shifts the CELIV peak to the right. If one uses Eq. (1) to extract the mobilities, we obtain values of 1.1×10^{-7} to $3.0 \times 10^{-9} \text{ m}^2 \text{ V}^{-1} \text{ s}^{-1}$. Thus, we can dete





graph that CELIV is measuring an averaged carrier mobil-ity (as described by Eq. (2)), which includes the influence of carrier trap starks. As was discussed above, carrier mobility in organic simonolactors is havon to change as a function of applied bias and as the CELIV technique intrinsically uses a voltage maps to text technicap from the device. An obvious aper-tion to as it, is how much does the application of a voltage maps to the cell ducts the means and nonliky. Figure 3 years er mobility within the device as a fu calculated using Eq. (2). It can be seen that the ithin the device chances by un to an order of mar-

itude within the CELIV transient and by up to 50% befor peak of the transient. If the trap density and applied voltage both affect the ent, then we should ask how good a m nent of mobility is the CELIV method in general? To an question, a series of CELIV simulations were red where the free electron and hole mobilities $(\mu_{e/b}^0)$ it equal and varied together from $\mu_e^0 = \mu_b^0 = 1 \times 10^{-6}$ 1. Equation (1) was used to extract the from the CELIV transients and Eq. (2) used to a effective mobility from the model before the ansient started. This was repeated for energetic tail ing the tail an be seen that the CELIV method I ue the CELIV der extracted from the device as a sincle well of width l(x) depleted of charge behind and side of Figure 5). With the addition of disord carriers in shallow traps can becom





extention with Eq. (2) plotted against

speciage manna size of Figure 3); mis is because during t application of the CELIV voltage ramp the quasi-Fermi le el(s) of the free carriers will progressively move to low energies forcing ever more dooily transmit states to a setas shallowly transed carr han a single uniform charge sheet I levice, charge is removed progressive deeper traps across the entire device. This n sheet (and region /(x)) in the CELP



with traps

the CELIV transient upon

J. Rash, Y. Dvalenov, and C. Deihel, Pros. Rev. B 56, 1153



- Literature reviews, can be of any length
- This is a short one, they can be multiple pages
- Or even whole books.
Literature review



- What is a literature review?
 - It is a **summary** of all the **key literature** published **in a field**.
- Why write a literature review?
 - To show your reader (your supervisor) that you have read, and understand the main published works in your field.
 - They are also very useful to read if you are just getting into a field (They are sometimes called **review articles**).
- Coursework 1: will be to write a 3000 word (minimum) literature review on the topic if your MSc project.
- Due date on the last day of this term (Friday 7th April).

Literature review



- What a literature review should **not be**:
 - A description of what others have published in the form of a set of summaries
- What **should** a literature review be:
 - It should be a critical discussion, showing insight and an awareness of differing arguments, theories and approaches.
 - It should analyze of the relevant published work, linked at all times to your own purpose and rationale.

According to Caulley (1992) of La Trobe University:



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- Compare and contrast different authors' views on an issue
- Group authors who draw similar conclusions
- Criticise aspects of methodology
- Note areas in which authors are in disagreement
- Highlight exemplary studies
- Highlight gaps in research
- Show how your study relates to previous studies
- Show how your study relates to the literature in general
- Conclude by summarising what the literature says

The purposes of the review are:

- To define and limit the problem you are working on
- To place your study in an historical perspective
- To avoid unnecessary duplication
- To evaluate promising research methods
- To relate your findings to previous knowledge and suggest further research

In summary: A good literature review, therefore, is critical of what has been written, identifies areas of controversy, raises questions and identifies areas which need further research.



- You will need to group together, compare and contrast the varying opinions of different writers on certain topics.
- What you must not do is just describe what one writer says, then describe what the next writer says and so on ...
- Your structure should be dictated instead by topic areas, controversial issues or by questions to which there are varying approaches and theories. Within each of these sections, you would then discuss what the different literature argues, remembering to link this to your own purpose.
- If there is disagreement in the field, you need to indicate clearly that you are aware of this.
- At the end of the review you should include a summary of what the literature implies.

Overall stratagy



- Decide what you need to read, your supervisor may suggest one or two good papers to start with.
- Before you start reading it may be useful to compile a list of the main areas and questions involved, this list may change as you read.

Make sure that:

- You include a clear, short introduction which gives an outline of the review, including the main topics covered and the order of the arguments, with a brief rationale for this.
- Split your review up into relevant subsections based around topics in your field.
- Include a short summary at the end of each section.
- You always acknowledge opinions which do not agree with.
- If you ignore opposing viewpoints, your argument will in fact be weaker.



- When I'm learning about a new topic I try to find **easy to understand** things first.
- I always **start** with Wikipedia and general articles on the web (for an hour or so)
- I then use scholar.google.com to search for key words and try to identify key papers which look interesting.
- Then, try also to identify key people or groups working on a topic and find what they are doing.
- Figure out who you respect in a field and who you don't respect.
- Follow references at the bottom of papers.

Lecture outline



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